

# MIC94051YM4-TR Datasheet



DiGi Electronics Part Number	MIC94051YM4-TR-DG
Manufacturer	Microchip Technology
Manufacturer Product Number	MIC94051YM4-TR
Description	MOSFET P-CH 6V 1.8A SOT143
Detailed Description	P-Channel 6 V 1.8A (Ta) 568mW (Ta) Surface t SOT-143

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MIC94051YM4-TR	Microchip Technology
Series:	Product Status:
SymFET™	Active
FET Type:	Technology:
P-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
6 V	1.8A (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
1.8V, 4.5V	160mOhm @ 100mA, 4.5V
Vgs(th) (Max) @ ld:	Vgs (Max):
1.2V @ 250µA	6V
Input Capacitance (Ciss) (Max) @ Vds:	FET Feature:
600 pF @ 5.5 V	
Power Dissipation (Max):	Operating Temperature:
568mW (Ta)	-40°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Surface Mount	SOT-143
Package / Case:	Base Product Number:
TO-253-4, TO-253AA	MIC94051

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	



# MIC94050/94051

4-Terminal SymFET<sup>™</sup> P-Channel MOSFET

SvmFET™

#### **General Description**

The MIC94050 and MIC94051 are 4-terminal silicon gate P-channel MOSFETs that provide low on-resistance in a very small package.

Designed for high-side switch applications where space is critical, the MIC94050/1 exhibits an on-resistance of typically  $0.125\Omega$  at 4.5V gate-to-source voltage. The MIC94050/1 also operates with only 1.8V gate-to-source voltage.

The MIC94050 is the basic 4-lead P-channel MOSFET. The MIC94051 is a variation that includes an internal gate pullup resistor that can reduce the system parts count in many applications.

The 4-terminal SOT-143 package permits a substrate connection separate from the source connection. This 4-terminal configuration improves the  $\theta_{JA}$  (improved heat dissipation) and makes reverse-blocking switch applications practical.

The small size, low threshold, and low  $R_{DS(on)}$  make the MIC94050/1 the ideal choice for PCMCIA, USB, back-up battery-power, and distributed power management applications.

#### Features

- 0.125Ω typical on-resistance at 4.5V gate-to-source voltage
- · Operates with 1.8V gate-to-source voltage
- · Separate substrate connection allows reverse-blocking

#### Applications

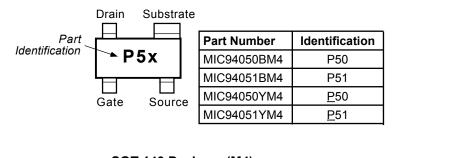
- Distributed power management
- PCMCIA card power management
- · USB ports
- · Battery-powered computers, peripherals
- · Handheld bar-code scanners
- Portable communications equipment
- Reverse blocking battery management

#### **Ordering Information**

Part Number	Temp. Range*	Package	Pb-FREE
MIC94050BM4	-40°C to +150°C	SOT-143	NO
MIC94051BM4	-40°C to +150°C	SOT-143	NO
MIC94050YM4	-40°C to +150°C	SOT-143	YES
MIC94051YM4	–40° to +150°C	SOT-143	YES

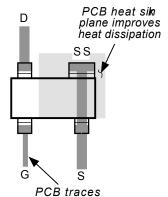
\* Operating Junction Temperature

## Pin Configuration

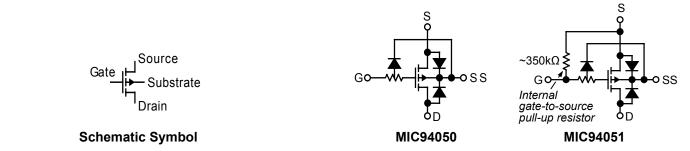


SOT-143 Package (M4)

## **Typical PCB Layout**



#### Functional Diagrams



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Schematic Symbol

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## **Absolute Maximum Ratings**

Drain-to-Source Voltage6V
Gate-to-Source Voltage6V
Continuous Drain Current
$T_A = 25^{\circ}C (V_{GS} = 4.5V) \dots 1.8A$
$T_A^{T} = 100^{\circ}C (V_{GS} = 4.5V) \dots 1.2A$
Total Power Dissipation
T <sub>A</sub> = 25°C568mW
T <sub>A</sub> = 100°C227mW
Operating Junction Temperature40°C to +150°C
Storage Temperature–55°C to +150°C
ESD Rating, Note 2

# **Operating Ratings**

#### Thermal Resistance

θ <sub>JA</sub>	
θ <sub>JC</sub>	

### **Electrical Characteristics (Note 1)**

Symbol	Parameter	Condition (Note 1)	Min	Тур	Max	Units
V <sub>GS</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	0.5		1.2	V
I <sub>GSS</sub>	Gate-Body Leakage	V <sub>DS</sub> = 0V, V <sub>GS</sub> = -4.5V, Note 2, Note 3			1	μA
R <sub>GS</sub>	Gate-Source Resistance	V <sub>DS</sub> = 0V, V <sub>GS</sub> = -4.5V, Note 2, Note 4	200	350	500	kΩ
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = -5.5V		600		pF
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -5.5V, V <sub>GS</sub> = 0V			1	μA
		V <sub>DS</sub> = –5.5V, V <sub>GS</sub> = 0V, T <sub>J</sub> = 85°C			5	μA
R <sub>DS(ON)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -100mA		0.125	0.160	Ω
20(011)		$V_{GS} = -3.6V, I_{D} = -100mA$		0.135	0.180	Ω
		$V_{GS} = -2.5V, I_{D} = -100mA$		0.165	0.200	Ω
		$V_{GS}^{OS} = -1.8V, I_{D}^{O} = -100mA$		0.225	0.320	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = –5.5V, I <sub>D</sub> = –200mA, <b>Note 5</b>		3		S

Note 1.  $T_A = 25^{\circ}C$  unless noted. Substrate connected to source for all conditions.

Note 2. ESD gate

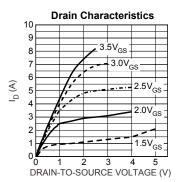
precautions required

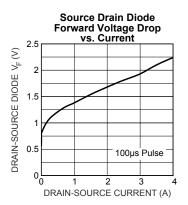
Note 3. MIC94050 only.

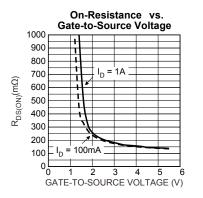
Note 4. MIC94051 only.

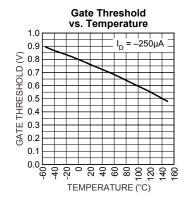
**Note 5.** Pulse Test: Pulse Width  $\leq 80\mu$ s, Duty Cycle  $\leq 0.5\%$ .

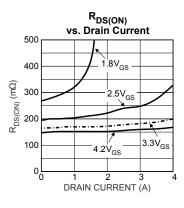
# **Typical Characteristics**

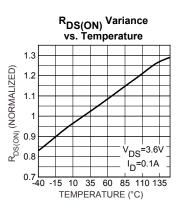




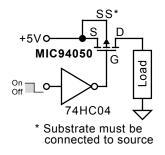








## **Typical Applications**





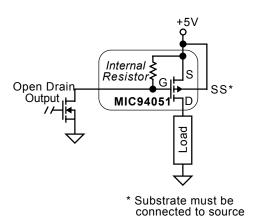
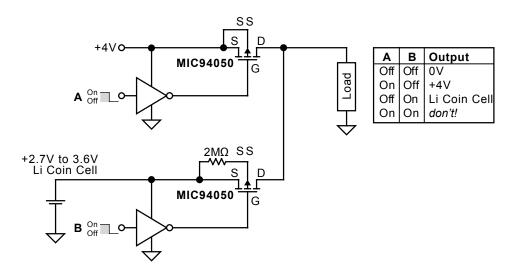
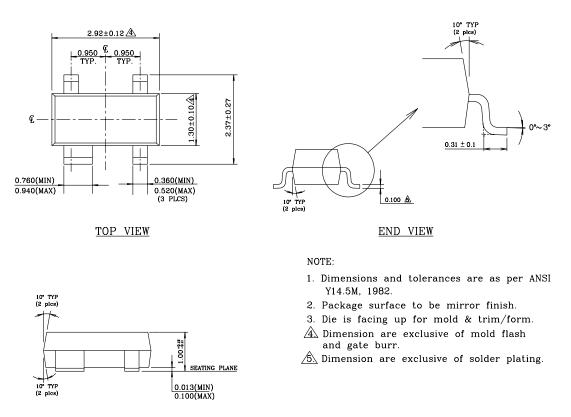


Figure 2. Load Switch Application (with internal gate-source pull-up)

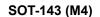




## Package Information



SIDE VIEW



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